SN74LV4051A 8-Channel Analog Multiplexers and Demultiplexers

1 Features

- 2-V to 5.5-V V_{CC} Operation
- Support Mixed-Mode Voltage Operation on All Ports
- High On-Off Output-Voltage Ratio
- Low Crosstalk Between Switches
- Individual Switch Controls
- Extremely Low Input Current
- Latch-Up Performance Exceeds 100-mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

2 Applications

- Telecommunications
- eCall
- Infotainment

3 Description

The SN74LV4051A 8-channel CMOS analog multiplexers and demultiplexers are designed for 2-V to 5.5-V V_{CC} operation.

The SN74LV4051A devices handle both analog and digital signals. Each channel permits signals with amplitudes up to 5.5-V (peak) to be transmitted in either direction.

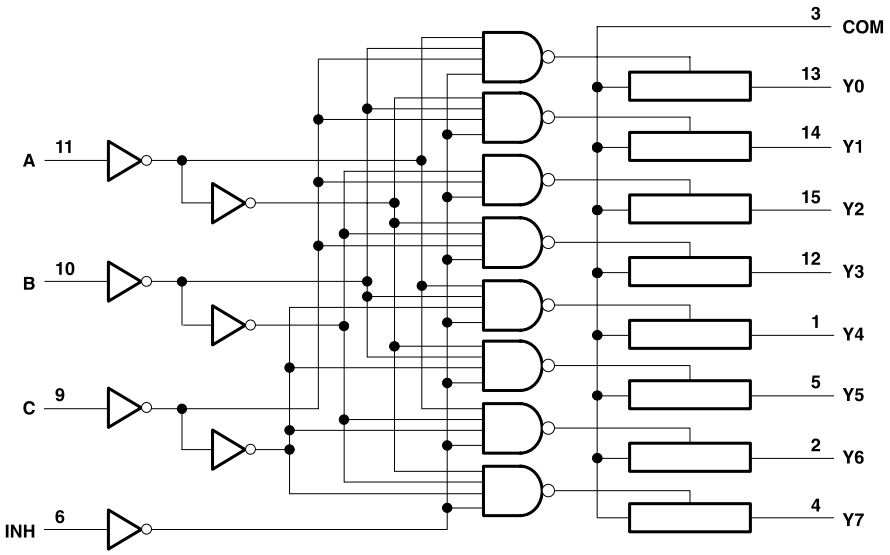
Applications include: signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

Device Information(1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74LV4051A	TSSOP (16)	5.00 mm × 6.30 mm
	SOIC (16)	9.90 mm × 6.00 mm
	SSOP (16)	6.20 mm × 7.80 mm
	TVSOP (16)	3.60 mm × 6.40 mm
	PDIP (16)	19.30 mm × 6.35 mm
	SO (16)	3.60 mm × 6.40 mm
	VQFN (16)	3.50 mm × 4.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Logic Diagram (Positive Logic)



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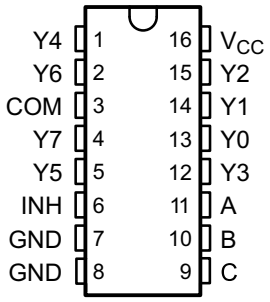
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

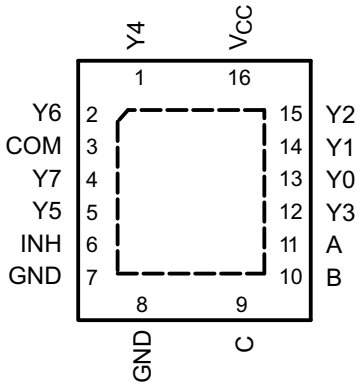
Changes from Revision H (April 2005) to Revision I	Page
• Added *Device Information* table, *Pin Functions* table, *ESD Ratings* table, *Thermal Information* table, *Detailed Description* section, *Applications and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section	1
• Deleted SN54LV4051A part number from the data sheet	1
• Removed *Ordering Information* table.	1
• Deleted θJA from the *Absolute Maximum Ratings* table	4

5 Pin Configuration and Functions

D, DB, DGB, N, NS, PW Package
16-Pin SOIC, SSOP, TVSOP, PDIP, SO, TSSOP
Top View



RGY Package
16-Pin VQFN With Exposed Thermal Pad
Top View



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
A	11	I	Selector line A for outputs (see *Device Functional Modes* for specific information)
B	10	I	Selector line B for outputs (see *Device Functional Modes* for specific information)
C	9	I	Selector line C for outputs (see *Device Functional Modes* for specific information)
COM	3	O/I(1)	Output/Input of mux
GND	7, 8	—	Ground
INH	6	I(1)	Enables the outputs of the device. Logic low level with turn the outputs on, high level will turn them off.
Y0	13	I/O(1)	Input/Output to mux
Y1	14	I/O(1)	Input/Output to mux
Y2	15	I/O(1)	Input/Output to mux
Y3	12	I/O(1)	Input/Output to mux
Y4	1	I/O(1)	Input/Output of mux
Y5	5	I/O(1)	Input/Output to mux
Y6	2	I/O(1)	Input/Output to mux
Y7	4	I/O(1)	Input/Output to mux
V_{CC}	16	—	Device power

(1) These I/O descriptions represent the device when used as a multiplexer, when this device is operated as a demultiplexer pins Y0-Y7 may be considered outputs (O) and the COM pin may be considered inputs (I).

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		–0.5	7.0	V
V_I	Input voltage range(2)		–0.5	7.0	V
V_{IO}	Switch I/O voltage range(2)(3)		–0.5	V_{CC} + 0.5	V
I_{IK}	Input clamp current	V_I < 0		−20	mA
I_{IOK}	I/O diode current	V_{IO} < 0		−50	mA
I_T	Switch through current	V_{IO} = 0 to V_{CC}		±25	mA
	Continuous current through V_{CC} or GND			±50	mA
T_J	Max Junction temperature			150	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
(3) This value is limited to 5.5-V maximum.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage		2(2)		5.5	V
V_{IH}	High-level input voltage, control inputs	V_{CC} = 2 V	1.5			V
		V_{CC} = 2.3 V to 2.7 V	V_{CC} × 0.7			
		V_{CC} = 3 V to 3.6 V	V_{CC} × 0.7			
		V_{CC} = 4.5 V to 5.5 V	V_{CC} × 0.7			
V_{IL}	Low-level input voltage, control inputs	V_{CC} = 2 V			0.5	V
		V_{CC} = 2.3 V to 2.7 V			V_{CC} × 0.3	
		V_{CC} = 3 V to 3.6 V			V_{CC} × 0.3	
		V_{CC} = 4.5 V to 5.5 V			V_{CC} × 0.3	
V_I	Control input voltage		0		5.5	V
V_{IO}	Input or output voltage		0		V_{CC}	V
Δt/Δv	Input transition rise or fall rate	V_{CC} = 2.3 V to 2.7 V			200	ns/V
		V_{CC} = 3 V to 3.6 V			100	
		V_{CC} = 4.5 V to 5.5 V			20	
T_A	Operating free-air temperature		–40		85	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to TI application report *Implications of Slow or Floating CMOS Inputs*, SCBA004.
(2) With supply voltages at or near 2 V, the analog switch ON-state resistance becomes very nonlinear. It is recommended that only digital signals be transmitted at these low supply voltages.

6.4 Thermal Information

THERMAL METRIC[1]		SN74LV4051A		UNIT
		N (PDIP)	PW (TSSOP)	
		16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	54.8	111.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	42.1	45.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	34.8	56.9	°C/W
ψ_{JT}	Junction-to-top characterization parameter	26.9	5.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	34.7	56.3	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		V_{CC}	MIN	TYP	MAX	UNIT
r_{on}	ON-state switch resistance	I_T = 2 mA, V_I = V_{CC} or GND, V_{INH} = V_{IL} (see Figure 2)	T_A = 25°C	2.3 V		38	180	Ω
			T_A = –40°C to 85°C				225	
			T_A = 25°C	3 V		30	150	
			T_A = –40°C to 85°C				190	
			T_A = 25°C	4.5 V		22	75	
			T_A = –40°C to 85°C				100	
$r_{on(p)}$	Peak ON-state resistance	I_T = 2 mA, V_I = V_{CC} to GND, V_{INH} = V_{IL}	T_A = 25°C	2.3 V		113	500	Ω
			T_A = –40°C to 85°C				600	
			T_A = 25°C	3 V		54	180	
			T_A = –40°C to 85°C				225	
			T_A = 25°C	4.5 V		31	100	
			T_A = –40°C to 85°C				125	
Δr_{on}	Difference in ON-state resistance between switches	I_T = 2 mA, V_I = V_{CC} to GND, V_{INH} = V_{IL}	T_A = 25°C	2.3 V		2.1	30	Ω
			T_A = –40°C to 85°C				40	
			T_A = 25°C	3 V		1.4	20	
			T_A = –40°C to 85°C				30	
			T_A = 25°C	4.5 V		1.3	15	
			T_A = –40°C to 85°C				20	
I_I	Control input current	V_I = 5.5 V or GND	T_A = 25°C	0 to 5.5 V			±0.1	μA
			T_A = –40°C to 85°C				±1	
$I_{S(off)}$	OFF-state switch leakage current	V_I = V_{CC} and V_O = GND, or V_I = GND and V_O = V_{CC}, V_{INH} = V_{IH} (see Figure 3)	T_A = 25°C	5.5 V			±0.1	μA
			T_A = –40°C to 85°C				±1	
$I_{S(on)}$	ON-state switch leakage current	V_I = V_{CC} or GND, V_{INH} = V_{IL} (see Figure 4)	T_A = 25°C	5.5 V			±0.1	μA
			T_A = –40°C to 85°C				±1	
I_{CC}	Supply current	V_I = V_{CC} or GND	T_A = –40°C to 85°C	5.5 V			20	μA
C_{IC}	Control input capacitance	f = 10 MHz	T_A = 25°C	3.3 V		2		pF
C_{IS}	Common terminal capacitance	T_A = 25°C		3.3 V		23.4		pF
C_{OS}	Switch terminal capacitance	T_A = 25°C		3.3 V		5.7		pF
C_F	Feedthrough capacitance	T_A = 25°C		3.3 V		0.5		pF

6.6 Operating Characteristics

V_{CC} = 3.3 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance	C_L = 50 pF,	f = 10 MHz	5.9	pF

6.7 Switching Characteristics: V_{CC} = 2.5 V ± 0.2 V

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		MIN	TYP	MAX	UNIT
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 15 pF (see Figure 5)	T_A = 25°C		1.9	10	ns
					T_A = –40°C to 85°C			16	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 15 pF (see Figure 6)	T_A = 25°C		6.6	18	ns
					T_A = –40°C to 85°C			23	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 15 pF (see Figure 6)	T_A = 25°C		7.4	18	ns
					T_A = –40°C to 85°C			23	
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 50 pF (see Figure 6)	T_A = 25°C		3.8	12	ns
					T_A = –40°C to 85°C			18	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 50 pF (see Figure 6)	T_A = 25°C		7.8	28	ns
					T_A = –40°C to 85°C			35	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 50 pF (see Figure 6)	T_A = 25°C		11.5	28	ns
					T_A = –40°C to 85°C			35	

6.8 Switching Characteristics: V_{CC} = 3.3 V ± 0.3 V

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		MIN	TYP	MAX	UNIT
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 15 pF (see Figure 5)	T_A = 25°C		1.2	6	ns
					T_A = –40°C to 85°C			10	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 15 pF (see Figure 6)	T_A = 25°C		4.7	12	ns
					T_A = –40°C to 85°C			15	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 15 pF (see Figure 6)	T_A = 25°C		5.7	12	ns
					T_A = –40°C to 85°C			15	
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 50 pF (see Figure 5)	T_A = 25°C		2.5	9	ns
					T_A = –40°C to 85°C			12	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 50 pF (see Figure 6)	T_A = 25°C		5.5	20	ns
					T_A = –40°C to 85°C			25	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 50 pF (see Figure 6)	T_A = 25°C		8.8	20	ns
					T_A = –40°C to 85°C			25	

6.9 Switching Characteristics: V_{CC} = 5 V ± 0.5 V

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		MIN	TYP	MAX	UNIT
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 15 pF (see Figure 5)	T_A = 25°C		0.6	4	ns
					T_A = –40°C to 85°C			7	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 15 pF (see Figure 6)	T_A = 25°C		3.5	8	ns
					T_A = –40°C to 85°C			10	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 15 pF (see Figure 6)	T_A = 25°C		4.4	8	ns
					T_A = –40°C to 85°C			10	
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 50 pF (see Figure 5)	T_A = 25°C		1.5	6	ns
					T_A = –40°C to 85°C			8	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 50 pF (see Figure 6)	T_A = 25°C		4	14	ns
					T_A = –40°C to 85°C			18	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 50 pF (see Figure 6)	T_A = 25°C		6.2	14	ns
					T_A = –40°C to 85°C			18	

6.10 Analog Switch Characteristics

over recommended operating free-air temperature range (unless otherwise noted), T_A = 25°C

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		V_{CC}	MIN	TYP	MAX	UNIT
Frequency response (switch on)	COM or Yn	Yn or COM	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (sine wave) (see(1) and Figure 7)		2.3 V		20		MHz
					3 V		25		
					4.5 V		35		
Crosstalk (control input to signal output)	INH	COM or Yn	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (square wave) (see Figure 8)		2.3 V		20		mV
					3 V		35		
					4.5 V		60		
Feedthrough attenuation (switch off)	COM or Yn	Yn or COM	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (see(2) and Figure 9)		2.3 V		–45		dB
					3 V		–45		
					4.5 V		–45		
Sine-wave distortion	COM or Yn	Yn or COM	C_L = 50 pF, R_L = 10 kΩ, f_{in} = 1 kHz (sine wave) (see Figure 10)	V_I = 2 V_{p-p}	2.3 V		0.1%		
				V_I = 2.5 V_{p-p}	3 V		0.1%		
				V_I = 4 V_{p-p}	4.5 V		0.1%		

(1) Adjust f_{in} voltage to obtain 0-dBm output. Increase f_{in} frequency until dB meter reads –3 dB.
(2) Adjust f_{in} voltage to obtain 0-dBm input.

6.11 Typical Characteristics

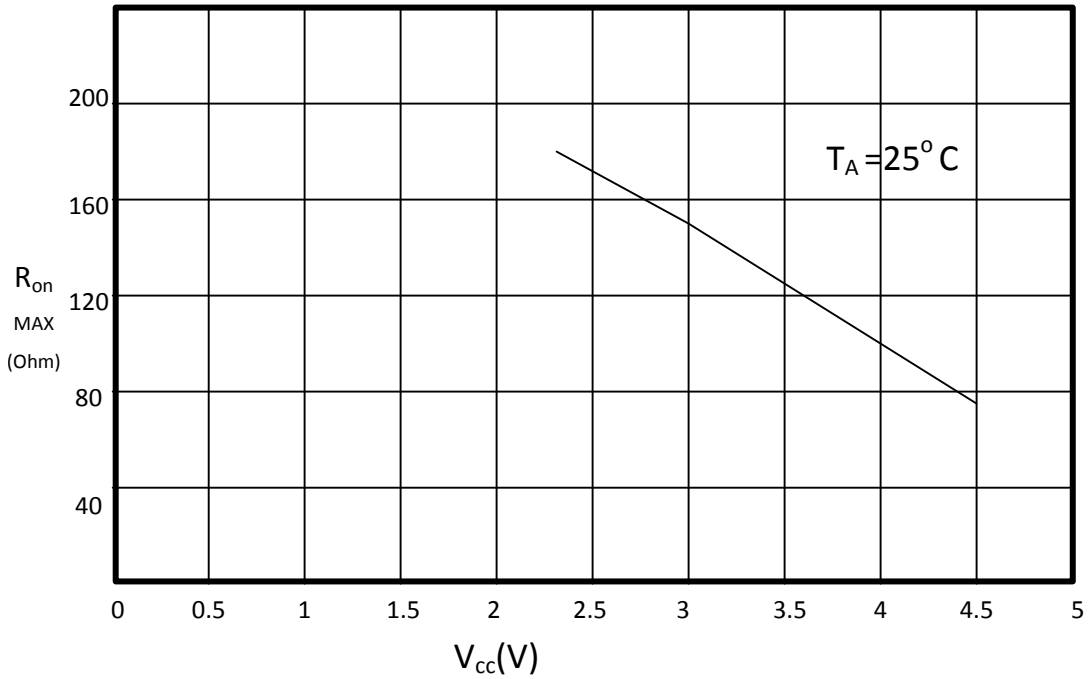


Figure 1. Plot at 25°C for V_{CC} vs Max R_{ON}

7 Parameter Measurement Information

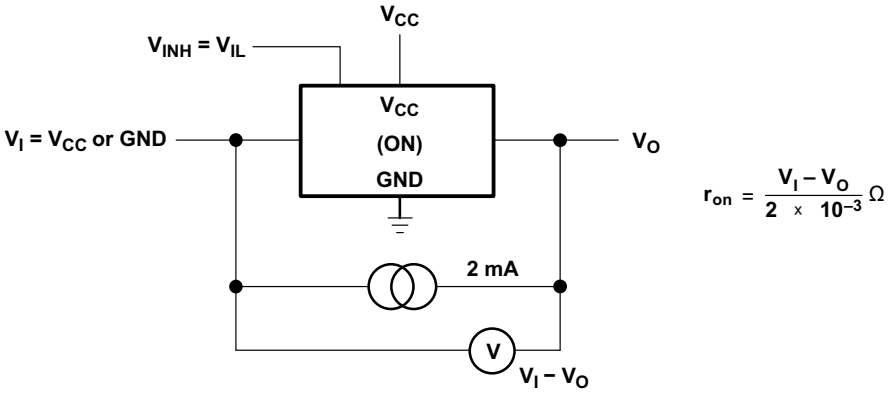


Figure 2. On-State Resistance Test Circuit

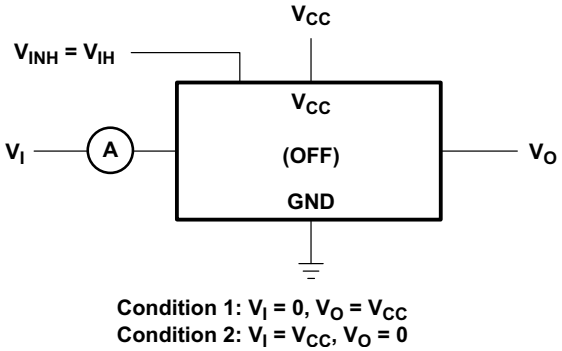


Figure 3. Off-State Switch Leakage-Current Test Circuit

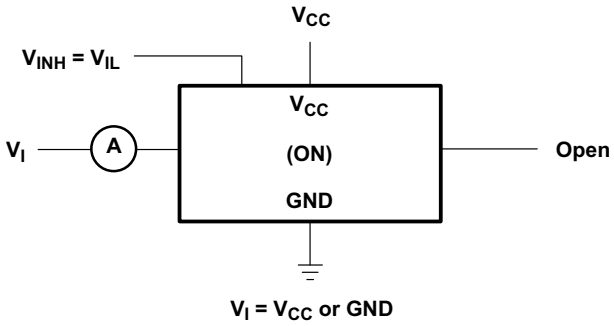


Figure 4. On-State Switch Leakage-Current Test Circuit

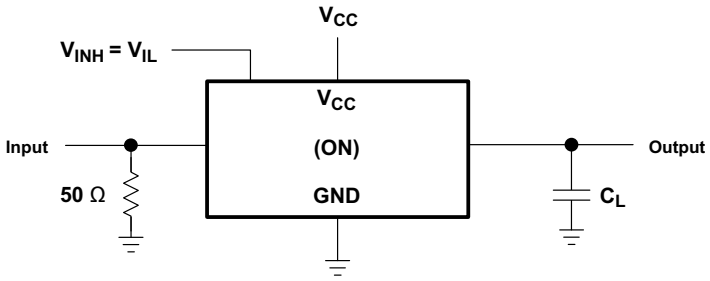
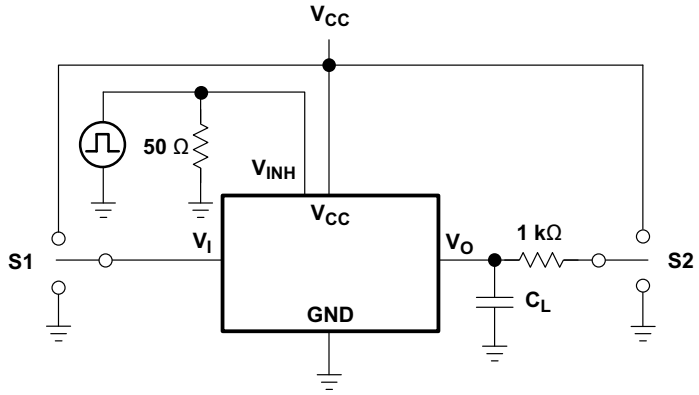


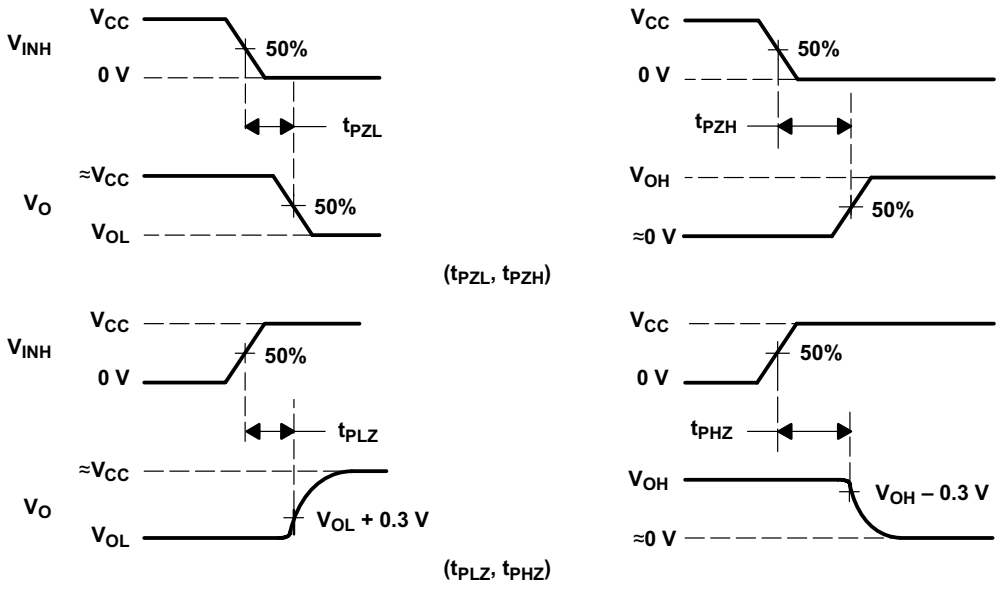
Figure 5. Propagation Delay Time, Signal Input to Signal Output

Parameter Measurement Information (continued)



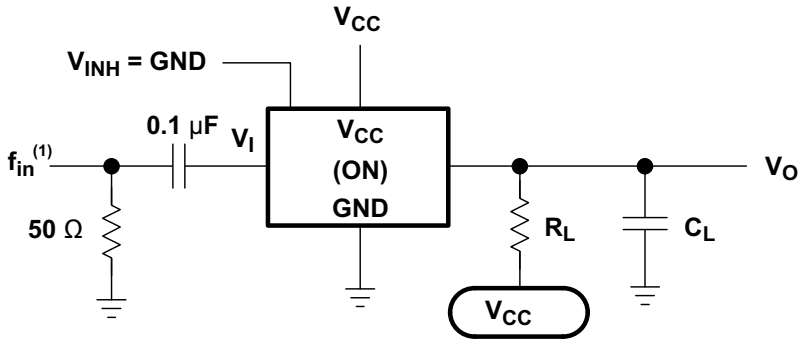
TEST	S1	S2
t_{PLZ}/t_{PZL} t_{PHZ}/t_{PZH}	GND V_{CC}	V_{CC} GND

TEST CIRCUIT



VOLTAGE WAVEFORMS

Figure 6. Switching Time (t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}), Control to Signal Output



(1) f_{in} is a sine wave.

Figure 7. Frequency Response (Switch On)

Parameter Measurement Information (continued)

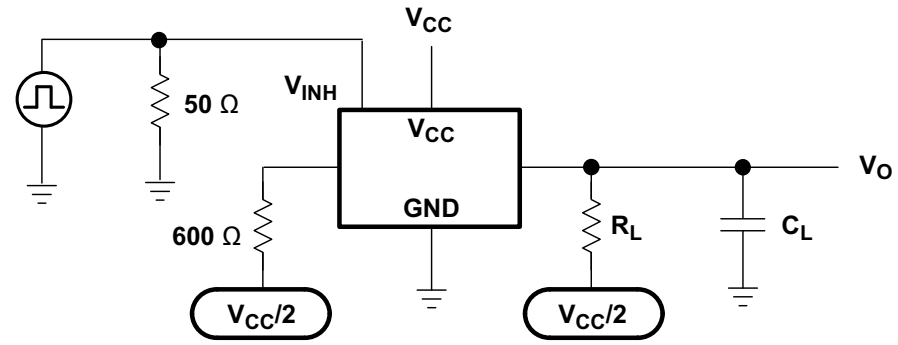


Figure 8. Crosstalk (Control Input, Switch Output)

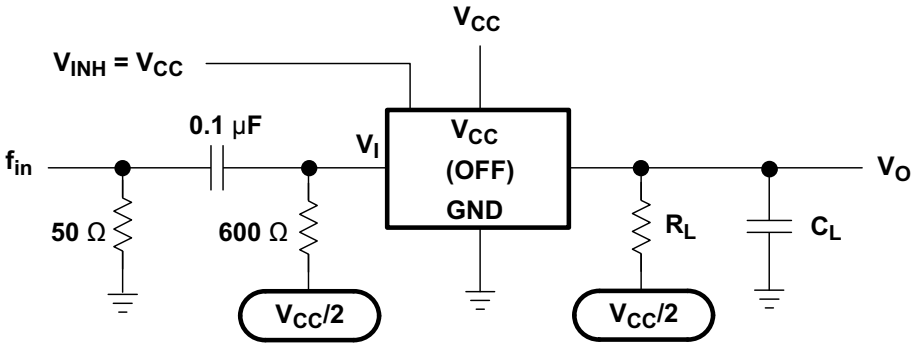


Figure 9. Feedthrough Attenuation (Switch Off)

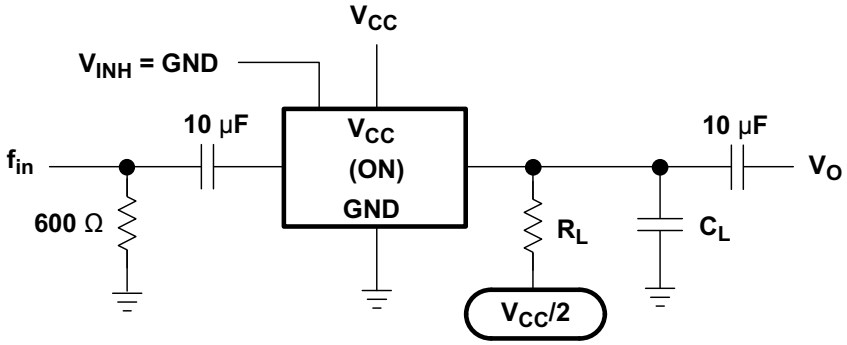


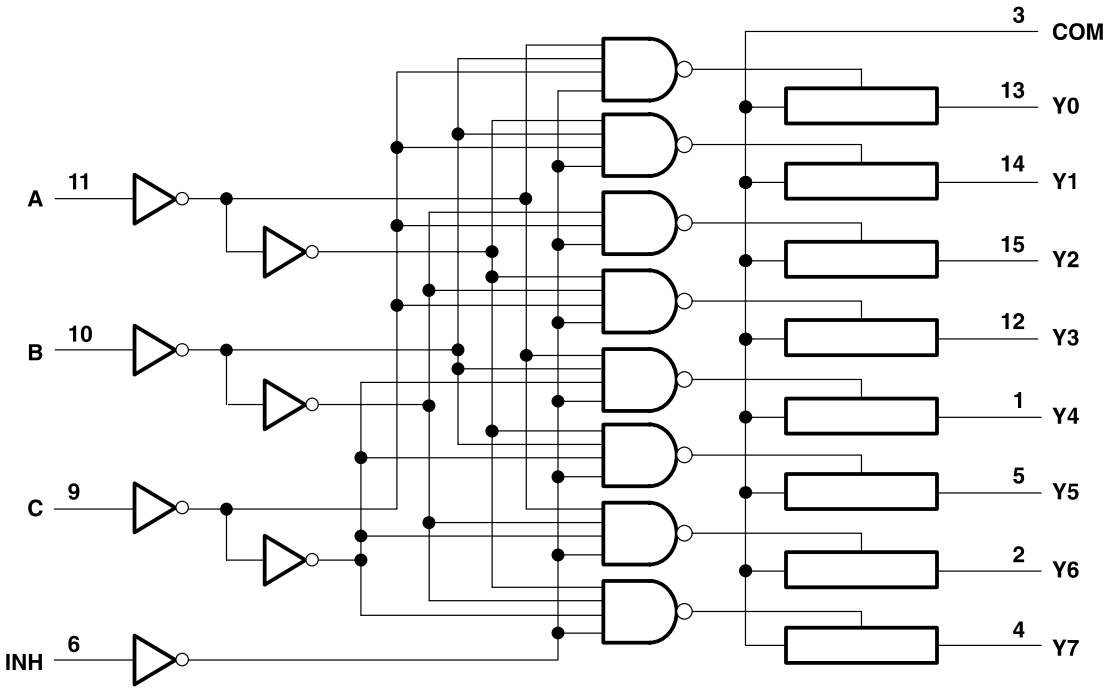
Figure 10. Sine-Wave Distortion

8 Detailed Description

8.1 Overview

The SN74LV4051A device is an 8-channel analog multiplexer. A multiplexer is used when several signals must share the same device or resource. This device allows for the selection of one of these signals at a time for analysis or propagation.

8.2 Functional Block Diagram



8.3 Feature Description

The SN74LV4051A device contains one 8-channel multiplexer for use in a variety of applications and can also be configured as demultiplexer by using the COM pin as an input and the Yn pins as outputs. This device is qualified to operate in the temperature range –40°C to +85°C (maximum depends on package type).

8.4 Device Functional Modes

Table 1. Function Table

INPUTS				ON CHANNEL
INH	C	B	A	
L	L	L	L	Y0
L	L	L	H	Y1
L	L	H	L	Y2
L	L	H	H	Y3
L	H	L	L	Y4
L	H	L	H	Y5
L	H	H	L	Y6
L	H	H	H	Y7
H	X	X	X	None

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

A multiplexer is used in applications where multiple signals share a resource. In Figure 11, several different sensors are connected to the analog-to-digital converter (ADC) of a microcontroller unit (MCU).

9.2 Typical Application

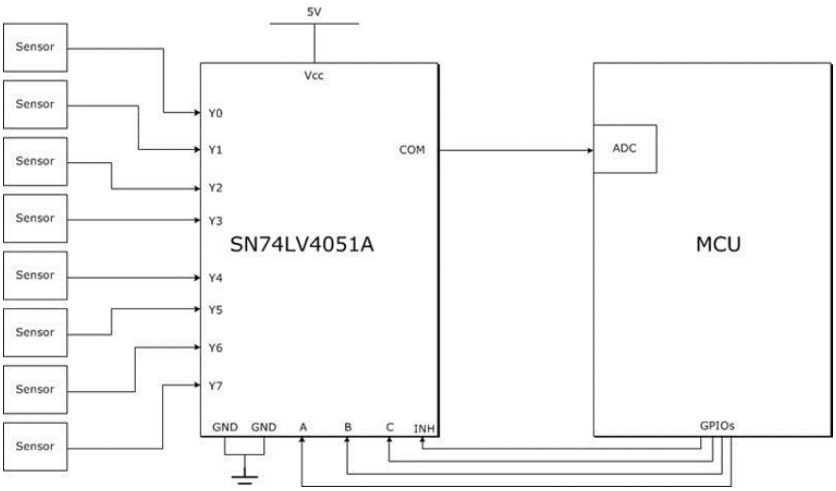


Figure 11. Example of Multiplexer Use With Analog Sensors and the ADC of an MCU

9.2.1 Design Requirements

Designing with the SN74LV4051A device requires a stable input voltage between 2 V (see *Recommended Operating Conditions* for details) and 5.5 V. Another important design consideration are the characteristics of the signal being multiplexed—ensure no important information is lost due to timing or incompatibility with this device.

9.2.2 Detailed Design Procedure

Normally, processing eight different analog signals requires eight separate ADCs, but Figure 11 shows how to achieve this using only one ADC and four GPIOs (general-purpose input/outputs).

Typical Application (continued)

9.2.3 Application Curve

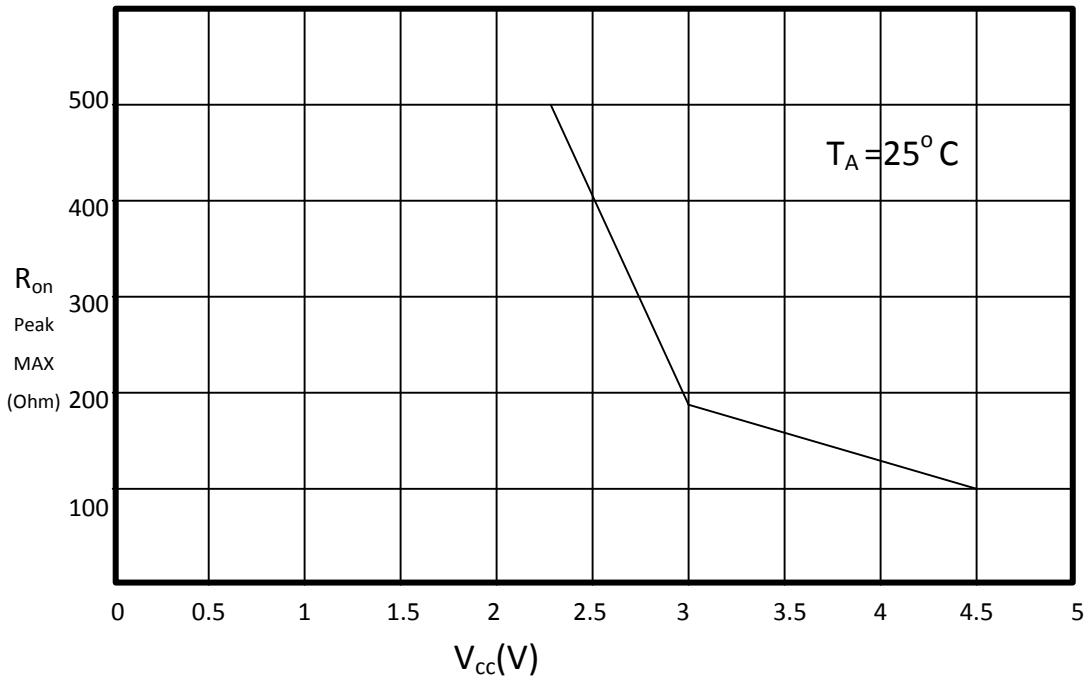


Figure 12. Plot at 25°C for V_{CC} vs Max $R_{ON(peak)}$

10 Power Supply Recommendations

Most systems have a common 3.3-V or 5-V rail that can supply the V_{CC} pin of this device. If this rail is not available, a switched-mode power supply (SMPS) or a low dropout regulator (LDO) can supply this device from a higher-voltage rail.

11 Layout

11.1 Layout Guidelines

TI recommends keeping the signal lines as short and as straight as possible (see Figure 13). Incorporation of microstrip or stripline techniques are also recommended when signal lines are more than 1" long. These traces must be designed with a characteristic impedance of either 50-Ω or 75-Ω as required by the application. Do **not** place this device too close to high-voltage switching components because they may cause interference.

11.2 Layout Example

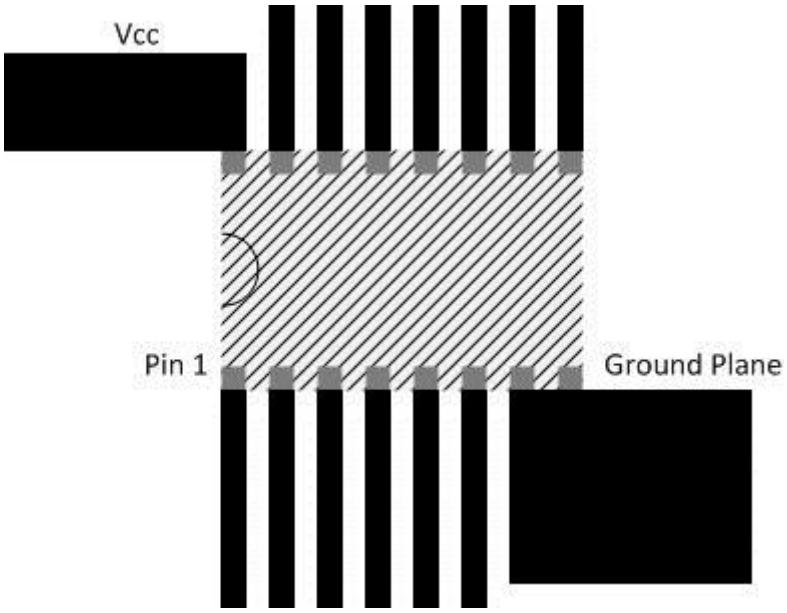


Figure 13. Layout Schematic

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation, see the following:

Implications of Slow or Floating CMOS Inputs, SCBA004

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community ***TI's Engineer-to-Engineer (E2E) Community.*** Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

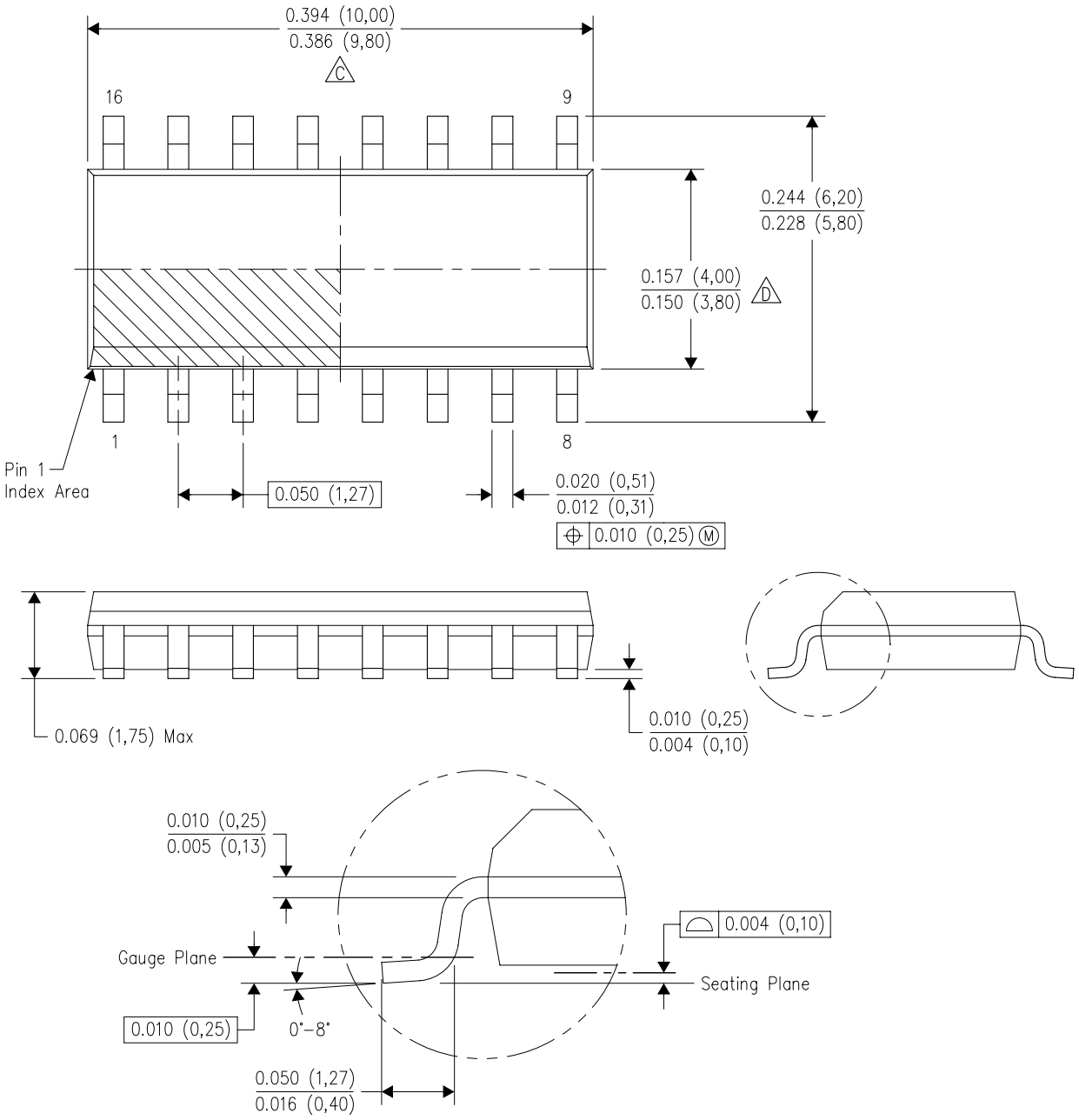
SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

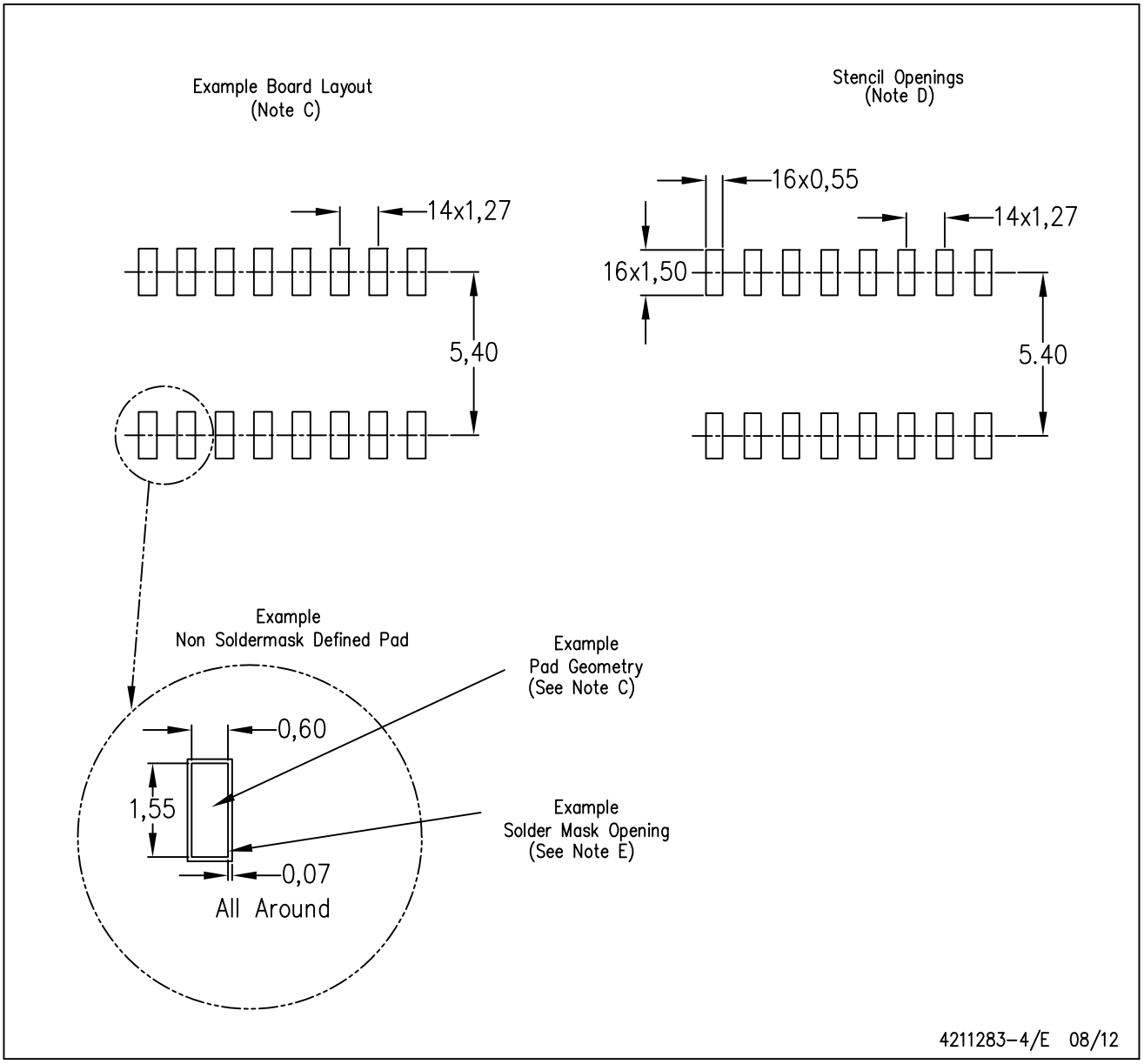
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

D (R–PDSO–G16) PLASTIC SMALL OUTLINE

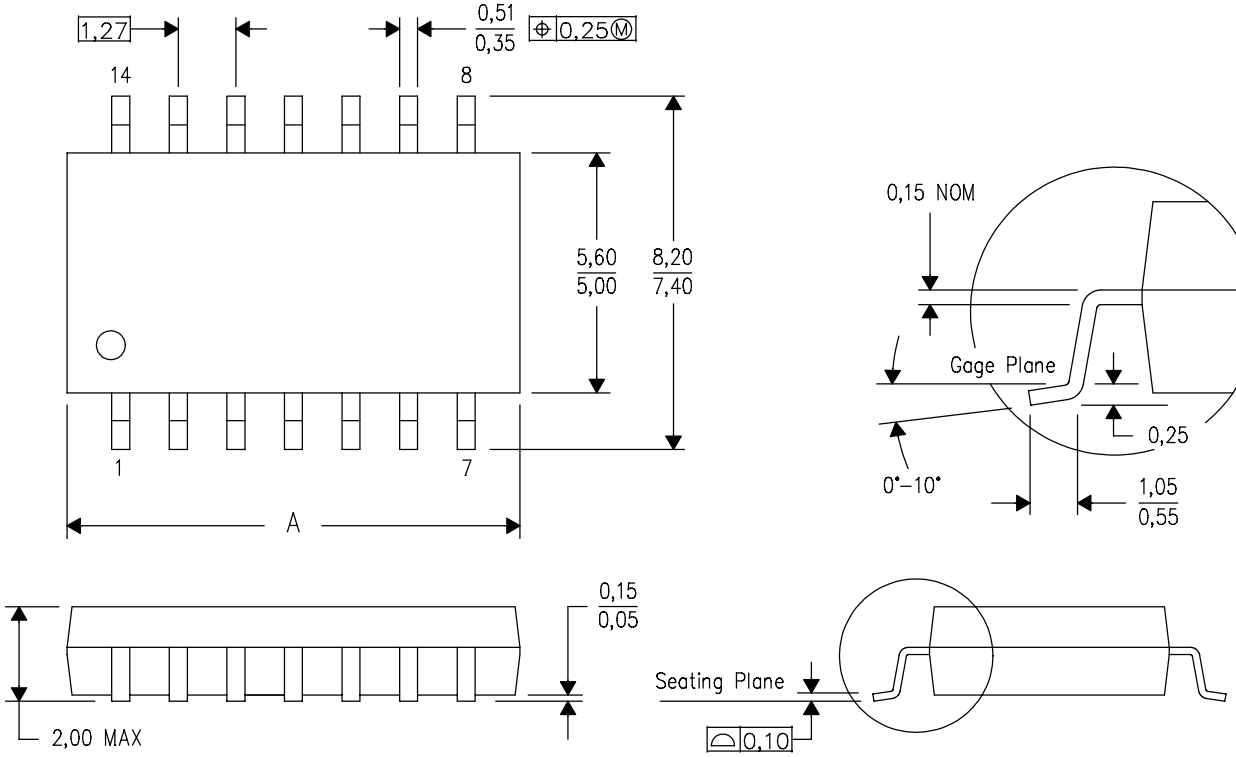


NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

MECHANICAL DATA

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN



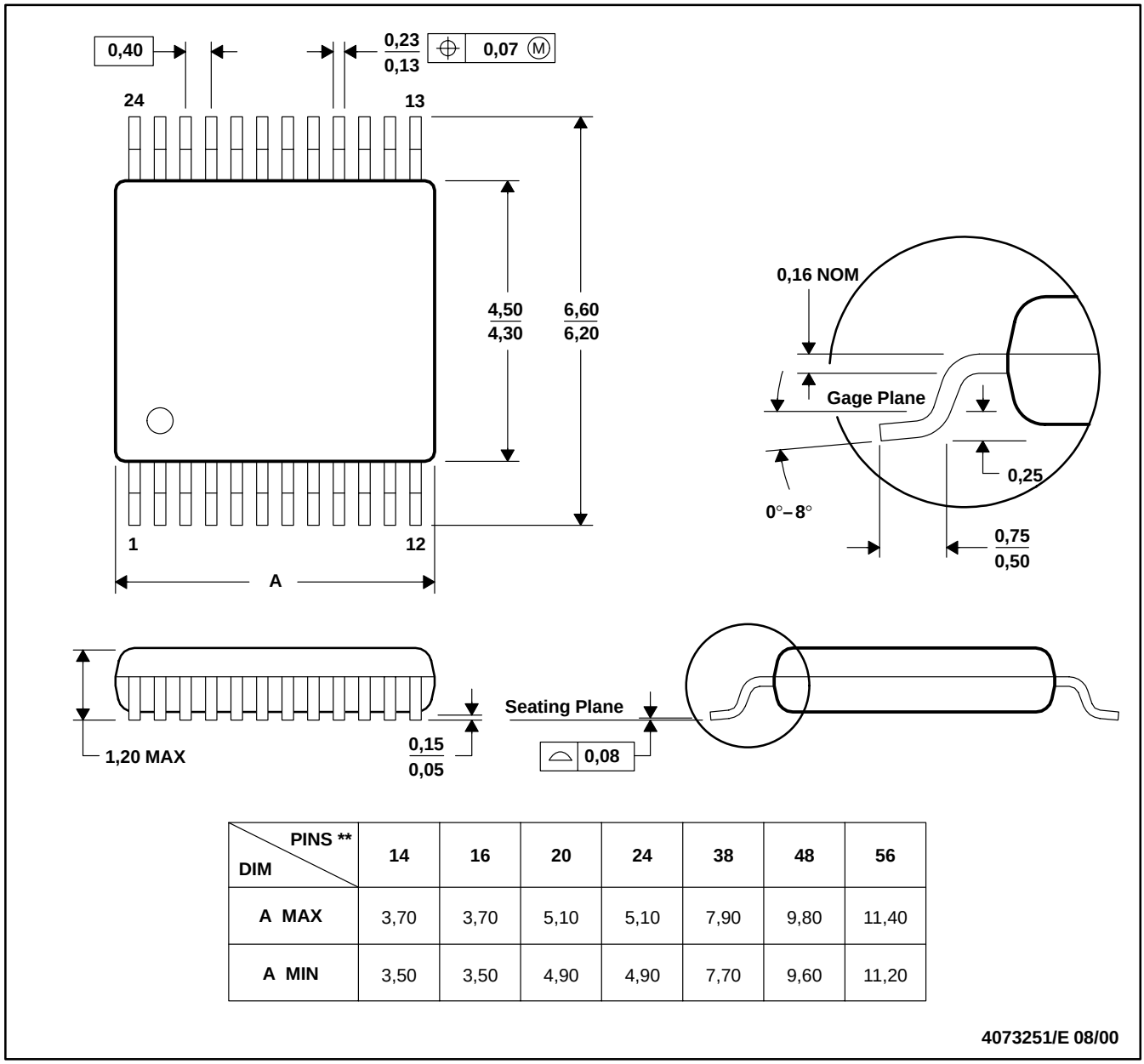
DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

DGV (R-PDSO-G)** **PLASTIC SMALL-OUTLINE**

24 PINS SHOWN

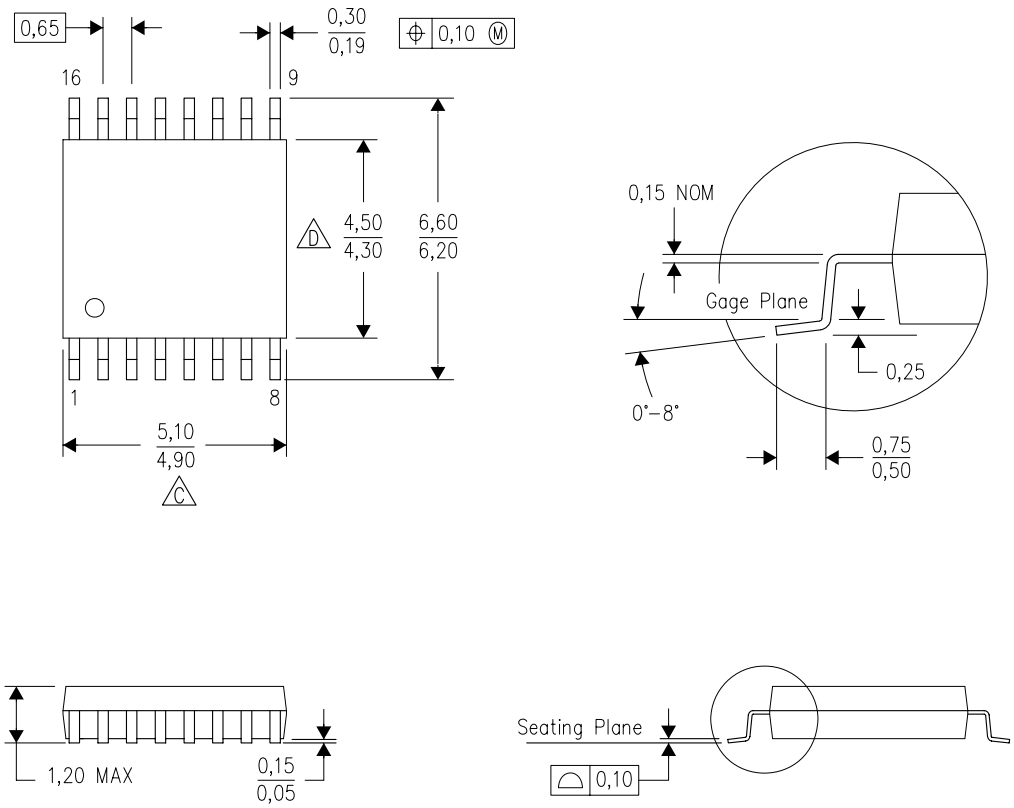


DIM \ PINS **	14	16	20	24	38	48	56
A MAX	3,70	3,70	5,10	5,10	7,90	9,80	11,40
A MIN	3,50	3,50	4,90	4,90	7,70	9,60	11,20

4073251/E 08/00

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
D. Falls within JEDEC: 24/48 Pins – MO-153
14/16/20/56 Pins – MO-194

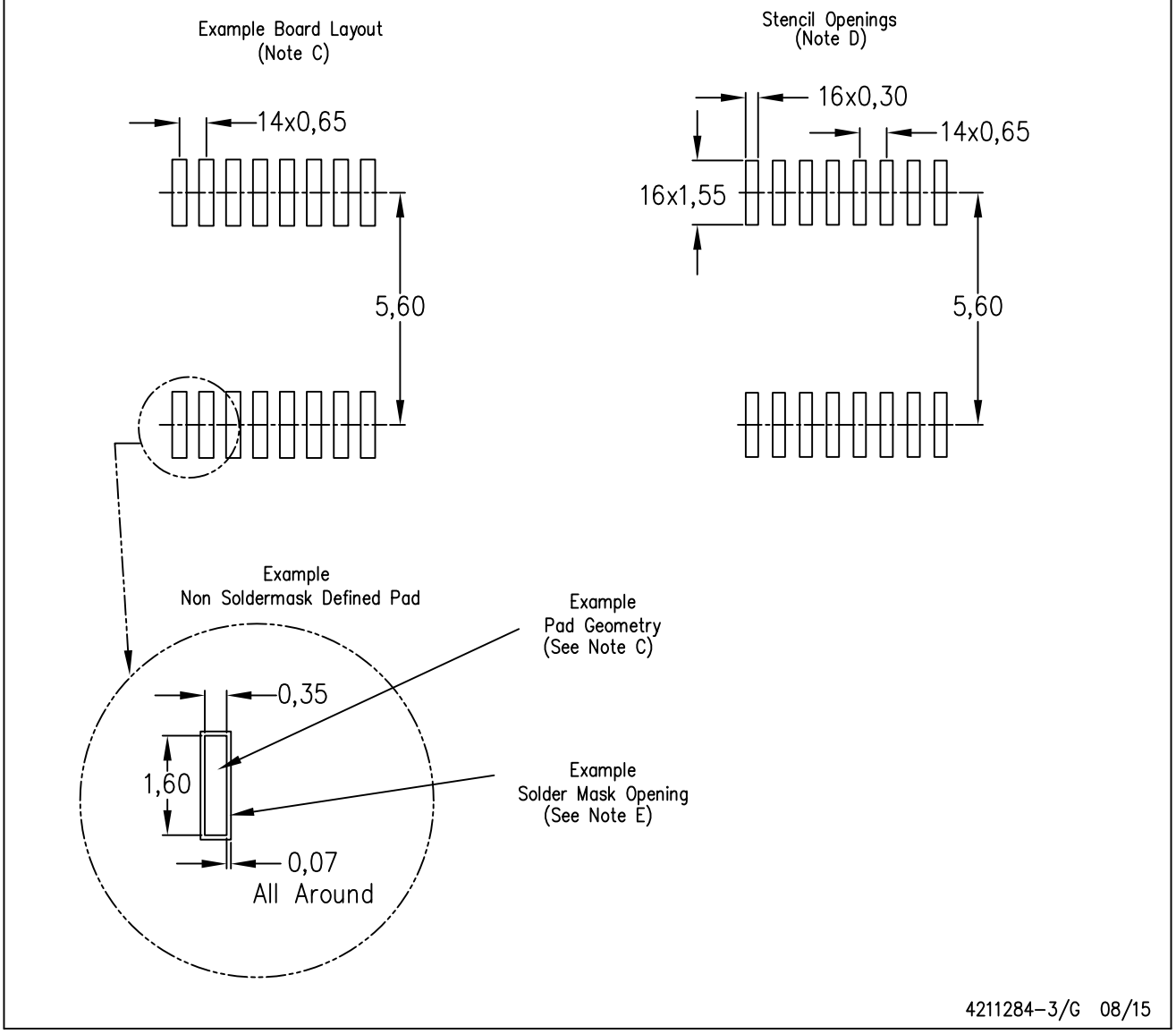
PW (R–PDSO–G16) PLASTIC SMALL OUTLINE



4040064–4/G 02/11

NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
E. Falls within JEDEC MO–153

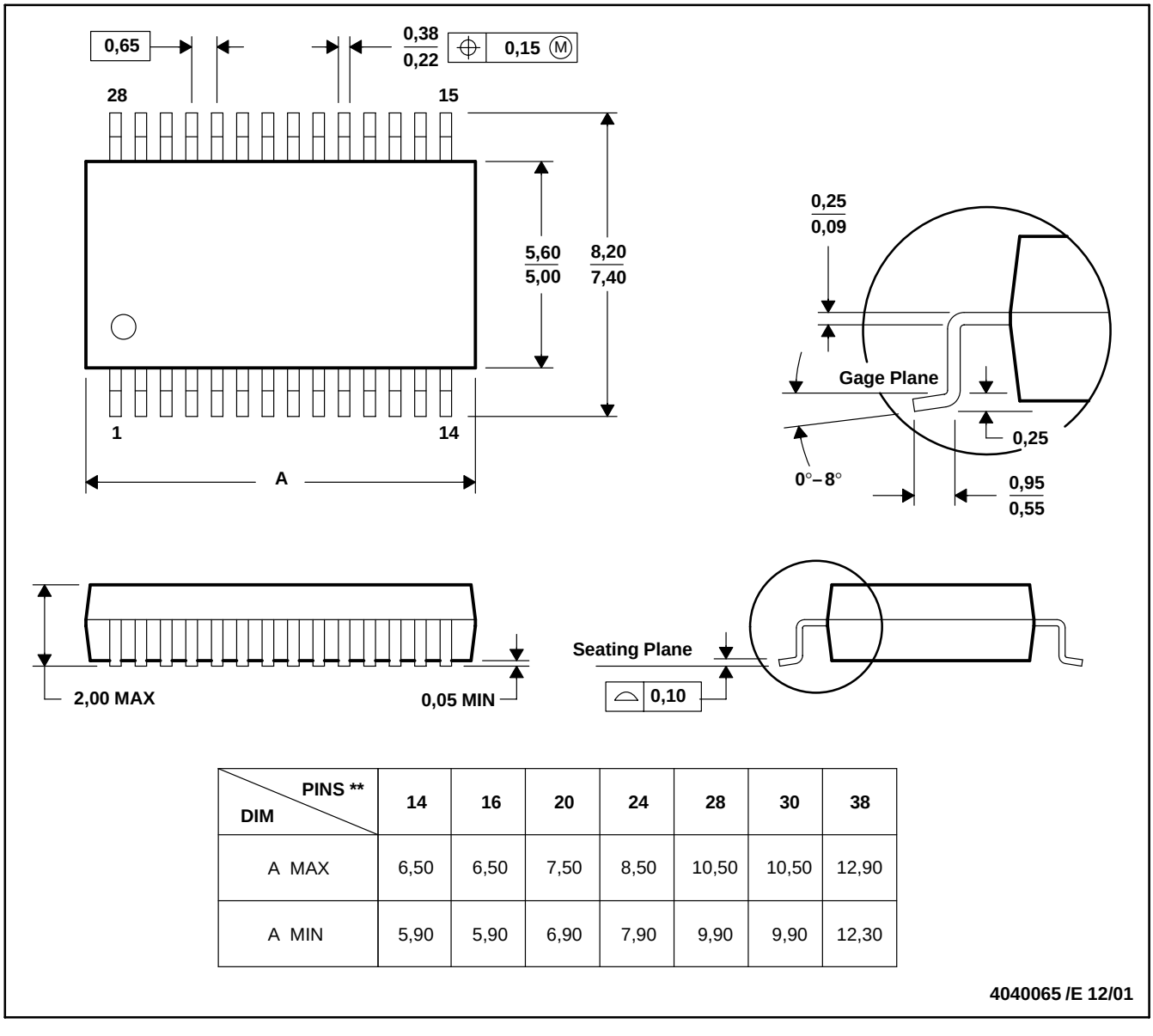
PW (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

DB (R-PDSO-G)** **PLASTIC SMALL-OUTLINE**

28 PINS SHOWN



DIM \ PINS **	14	16	20	24	28	30	38
A MAX	6,50	6,50	7,50	8,50	10,50	10,50	12,90
A MIN	5,90	5,90	6,90	7,90	9,90	9,90	12,30

4040065 /E 12/01

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-150